On the low-tem perature lattice therm al transport in nanow ires

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Abstract

We propose a theory of low temperature therm altransport in nano-wires in the regime where a competition between phonon and exural modes governs the relaxation processes. Starting with the standard kinetic equations for two dimensions of quasiparticles we derive a general expression for the conductivity. The underlying physics of thermal conductance is completely determined by the corresponding relaxation times, which can be calculated directly for any dispersion of quasiparticles depending on the size of a system. We show that if the considered relaxation mechanism is dominant, then at small wire diameters the temperature dependence of thermal conductivity experiences a crossover from $T^{1=2}$ to T^3 -dependence. Quantitative analysis show s reasonable agreement with resent experimental results.

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Low -dim ensional materials have attracted considerable attention in recent years, particularly, in view of their potential applications in electronic devices [1, 2]. M any theoretical and experim ental studies of nanow ires and nanotubes are centered on the properties of electronic transport. However it is realized now that the therm alproperties of nanom aterials are also in portant for applications [3, 4, 5]. It is of special interest to increase therm al conductance in the m icro and nanodevices [1, 6, 7]. In this paper study therm altransport in nonm etallic system s, in which heat is transported by therm all excitations only. In addition to practical in portance of such studies, therm altransport in nanow ires is interesting from fundam ental point of view. Recent theoretical [8] and experimental [9] ndings proved the existence of the quantum of them al conductance in ballistic regime, which is similar to the quantum of electronic conductance. The state of experim ental and theoretical understanding of therm al transport in nanoscale systems is comprehensively discussed in the review [10]. Recently D. Liet al [11] reported an accurate m easurem ent of lattice therm al conductivity in silicon nanow ires for a wide range of tem peratures and wire diam eters. They dem onstrated the signi cant in uence of the system size not only on the magnitude of the therm al conductivity coe cient, but also on its tem perature dependence. It is well known that for large enough diam eters of the wire and di usive phonon - boundary scattering, therm al conductivity coe cient at low tem peratures is proportional to T³. But for sm all values of the wire diam eters experim ent [11] show s clear crossover from cubic to near linear dependence on the tem perature. In the present paper we consider one particular relaxation mechanism which can explain the observed crossover.

Recently M ingo [12] carried out an accurate num erical study of them al conductance of silicon nanow ires to explain the decrease of the them al conductivity coe cient with w ire diam eter observed in the experim ent. H e assumed that all the elects can be explained by the reconstruction of the phonon dispersion, where realistic phonon m odes obtained from M D sin ulations were applied to general expression of the them al conductivity coe cient. H is num erical analysis show s excellent quantitative agreem ent with the experim ent [11] for large enough diam eters at high tem peratures. As the system size becomes smaller, the approach fails to describe a sharp decrease of therm al conductance as well as qualitative change of its tem perature dependence. This is likely because the M atheissen's rule has been used for evaluation of the phonon lifetim e, which has rather restricted range of applicability (see e.g. [13] and references therein).

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As it was noted in Ref. [14], decrease of the temperature increases the characteristic phonon wavelength and reduces the scattering probability at the boundary surface. This leads to a modi cation of the phonon spectrum. For ideal wires it is represented by a set of branches with energies proportional to 1D m om entum directed along the wire. So the standard theory of therm al conductance in dielectrics and sem iconductors has to be modi ed to account for low dimensionality e ects as well as phonon spectrum modi cation at low temperatures. Thus, to understand thoroughly the physical processes occurring inside the nanow ires with decreasing sizes, we need an analytical theory to account for di erent mechanism s explicitly, such as dispersion reconstruction and restricted geometry.

To approach the problem we consider low enough temperatures, where the quasiparticle states of "acoustic" branches are therm ally populated (! 0 when p! 0). The corresponding acoustic branches have the following dispersion relations [14, 15]:

$$_{1} = u_{1}p_{1}; \qquad _{2} = u_{2}ap_{2}^{2};$$
 (1)

where $_{\rm i}$ stands for the energy of a quasiparticle, $p_{\rm i}$ is the corresponding m om entum , a is the wire diameter, u_1 and u_2 are the characteristic velocities. The st expression in Eq. (1) is the phonon dispersion and the second expression is the dispersion of exural mode. The nature of exuralm odes com es from the fact they are analogous to bending m odes of classical elasticity theory, or the antisym metric Lamb waves of a free plate [16]. A ppearance of such a m ode is just a direct consequence of restricted geom etry, and under som e conditions it can be considered as the only size e ect in them altransport properties. Strictly speaking there are two modes for each type of dispersion, but we do not account for them separately since their contributions are qualitatively the same. Consequently, we have to solve the kinetic problem for two-component gas of quasiparticles. It is well known [13, 17, 18, 19, 20] that using simple Callaway form ula to estim ate the therm al conductivity coe cient in two-com ponent system s som etim es leads to serious confusions. Sim ple sum m ation of the relaxation rates, as is done in the majority of theoretical works, is questionable under many physical conditions. The dependence of the kinetic coe cients on di erent relaxation times is much more com plicated in reality. A courate method for calculation of the di usion coe cient in two-component gas of quasiparticles was proposed in Ref. [20]. Here we extend this form alism to therm al conductance problem .

To start, we consider a system of two types of quasiparticles. Their kinetics is described by equations for corresponding distribution functions f_i :

$$v_{i}\frac{\partial f_{i}}{\partial z} = \sum_{j=1}^{X^{2}} C_{ij}(f_{i};f_{j}) + C_{i3}(f_{i}); \quad i = 1;2:$$
(2)

where $C_{ij}(f_i; f_j)$ is the collision integral of them all excitations, and $C_{ij}(f_i)$ is the collision integral describing the scattering processes between quasiparticles and scatterers. In general the latter includes all the processes leading to the non-conservation of the total energy. $v_i = @_i = @p_i$ is the group velocity of the corresponding them all excitation. Them aim purpose of our theory is to obtain analytic expressions of them all conductance, which are applicable to quasiparticles with arbitrary dispersion relations. In other words, the explicit dispersion relations in Eq. (1) are needed only at the last stage when calculating corresponding relaxation times and them odynam ic quantities. A susual, we seek a perturbative solution of the system (2) in the form

$$f_i = f_i^{(0)} + f_i;$$
 (3)

where $f_i^{(0)}$ is the local equilibrium Bose-function and f_i $f_i^{(0)}$ represents small deviation from the equilibrium. The perturbation term can be conveniently chosen to be $f_i = q Q f_i^{(0)} = Q_i$ with g_i the new target functions. A fler the standard linearization procedure, Eq. (2) can be written in the following matrix form :

$$j \quad i\frac{1}{T}\frac{\partial T}{\partial z} = \hat{C}jgi; \tag{4}$$

where

$$j i = {}^{1V_1}_{2V_2}; jgi = {}^{g_1}_{g_2};$$

The 2D collision matrix \hat{C} can be decomposed into a sum of three terms, corresponding to dimerent relaxation mechanisms: $\hat{C} = \hat{J} + \hat{S} + \hat{U}$; where \hat{J} , with matrix elements $J_{ij} = C_{ik ij} + C_{ij} \begin{pmatrix} 1 & ij \end{pmatrix}$ ($k \in i$), describes the relaxation due to interaction between quasiparticles of dimerent types; \hat{S} ($S_{ij} = C_{ii ij}$) describes collisions between identical quasiparticles, and \hat{U} ($U_{ij} = C_{i3 ij}$) describes all the other relaxation mechanisms, which do not conserve total energy of the quasiparticle system. \hat{U} includes scattering on defects, boundaries, um klapp processes etc. [21] Here C_{ij} represent linearized collision operators. Let us de ne the scalar product of two-dimensional bra- and ket-vectors as follows [20]:

$$h j i = \begin{cases} X & X \\ (k j k) = \\ k = 1;2 \end{cases} \begin{pmatrix} X & 2 \\ k & k \\ k = 1;2 \end{cases} \begin{pmatrix} \varrho f_k^{(0)} \\ \varrho & k \end{pmatrix} d_k;$$
(5)

where $(_k j \text{ and } j_k)$ are the correspondent one-component vectors, d is the element of phase volume. Under this condition, the collision operator \hat{C} becomes herm itian. System (4) is the system of nonuniform linear integral equations. A coording to the general theory of integral equations the target solution jg in ust be orthogonal to the solution of corresponding uniform equations $\hat{C}j_{uni}i$. It is therefore convenient to write the form al solution of (4) so that the orthogonality condition hg j_{uni}i is in posed explicitly in the solution. For this purpose we de ne the projection operator \hat{P}_n onto the subspace orthogonal to the vector $j_{uni}i$, $\hat{P}_n = 1$ \hat{P}_c ; $\hat{P}_c = j_{uni}ih_{uni}j$: As a result, the form al solution of the system (4) can be written in the form

$$jgi = \hat{P}_n \quad \hat{C}^1 \quad \hat{P}_n j \quad i\frac{1}{T}\frac{\partial T}{\partial z}$$
: (6)

The heat ux density due to the therm al excitations of dimensity product types is given by the expression $Q = \begin{bmatrix} P & R \\ k=1,2 \end{bmatrix}$ $kv_k f_k d_k: U sing relation (3) and de nition of scalar product (5), Q can be rewritten as <math>Q = h$ jgi: On the other hand, the elective therm al conductivity coelected to the relation $Q = \int_{eff} QT = Qz$: C on paring the above two expressions for Q, and using the form al solution (6) we obtain

$$eff = \frac{1}{T}h \quad j\hat{C}^{1} j \quad i:$$
(7)

To derive an exact and analytical expression for them al conductivity coe cient (7) it is necessary to introduce a complete set of orthonorm al two-dimensional vectors $j_n i$ (n = 1;2;3; ...) belonging to the in nite-dimensional H ilbert space with scalar product (5). In principle, the particular choice of the basis is not essential, but for the convenience of calculations it is useful to specify at least four of them. It's convenient to chose the rst of them to correspond to the total momentum of quasiparticles and the second one to be orthogonal, but still linear in momentum [20]:

$$j_{1}i = \frac{1}{p_{-}} \begin{pmatrix} p_{1} \\ p_{2} \end{pmatrix}; \quad j_{2}i = \frac{1}{p_{-}} \begin{pmatrix} 2p_{1} \\ p_{2} \end{pmatrix}; \quad (8)$$

where $_{i} = (p_{i}\dot{p}_{i})$ is the norm aldensity of the ith component, $= _{1} + _{2}$. The third and the fourth vectors correspond to the energy ux:

$$j_{3}i = \frac{1}{N_{1}} 0^{1}; \quad j_{4}i = \frac{1}{N_{2}} 0^{+}; \quad (9)$$

where

$$j = \frac{p}{T} j v_j \frac{S_j T}{j} p_j ; \qquad (10)$$

and N_j = $p_{(jj_j)}$ is the corresponding normalization ∞ e cient. Partial entropy of quasiparticle subsystem S_j in eq. (10) is given by the relation

$$S_{j} = \frac{1}{T} (_{j} v_{j} \dot{p}_{j})$$
: (11)

Form ally, the kinetic problem of two-component quasiparticles system can be solved in the above basis set. The inversion of the operator matrix \hat{C} in Eq. (7) is similar to the procedure described in Ref. [20]. The nalresult contains in nite dimensional non-diagonal matrices. To obtain closed form expressions we must use some approximations, correct – approximation [19] or K inara approximation [20, 22, 23]. In some physical situations we are able to obtain closed analytical expressions. It is rigorously proved in [20] that in case of quasi-equilibrium within each subsystem of quasiparticles, the corresponding transport coe cient can be obtained in close analytical form. This is a reliable approximation when the low temperature relaxation is mainly governed by the defect scattering processes. The approximation form ally in plies that all the matrix elements of matrix \hat{S} in eq. (7) tend to in nity. The therm alconductivity coe cient in this case can be obtained in the form : $_{eff} = _{F} + _{D}$. Here we separate the ux part of therm alconductivity coe cient $_{F} = _{F} S^{2}T =$ with $S = S_{1} + S_{2}$, which approaches in nity when the quasiparticles do not interact with scatterers, and the di usive part $_{D} = _{D} (S_{1}T = _{1} - S_{2}T = _{2})^{2} - _{1} =^{T}$. The corresponding relaxation times are given by

$$_{\rm D} = \frac{1}{23} + \frac{2}{13} + \frac{1}{12} + \frac{1}{21} + \frac{1}{21} + \frac{1}{21}$$
(12)

and

$$F = D = \frac{S_1}{S} \frac{1}{2^3} + \frac{S_2}{S} \frac{1}{1^3} + \frac{1}{1^2} + \frac{1}{2^1} + \frac{1}{2^1} + \frac{1}{1^3} \frac{1}{2^3} + \frac{1}{1^2} \frac{1}{2^3} + \frac{1}{1^2} \frac{1}{2^3} + \frac{1}{2^1} \frac{1}{1^3} \frac{1}{1^3} + \frac{1}{1^3} \frac{1}{1^3} + \frac{1}{1^3} \frac{1}{1^3} \frac{1}{1^3} + \frac{1}{1^3} \frac{1}{1^3} \frac{1}{1^3} \frac{1}{1^3} + \frac{1}{1^3} \frac{$$

Relaxation times contained in formulas (12) - (13) are de ned by

$$_{kj}^{1} = \frac{1}{_{k}} (p_{j} \mathcal{F}_{kj} \dot{p}_{j}):$$
 (14)

We emphasize that they are not actual scattering times, which are momentum dependent, but are relaxation times associated with corresponding scattering mechanisms. Once we obtain the particular scattering rate $_{kj}(p_k)$ from standard scattering theory, we can replace true collision operator C_k with $_{kj}(p_k)$, so that the corresponding relaxation time can be calculated by

$${}_{kj}^{1} = {}_{k}^{1} p_{k}^{2} {}_{kj} (p_{k}) \frac{\theta f_{k}^{(0)}}{\theta_{k}} d_{k}$$
(15)

As can be seen from the derived form ulas, the coe cient of therm alconductivity contains di erent relaxation times in rather non-trivial combination. If drop out one component (say set $S_2 = 0$, $_2 = 0$) we recover the usual result $_F^{(1)} = {}_{13}S_1^2T = {}_1$. For phonons with linear dispersion = vp, $_F$ reduces to the well-known result $_F^{ph} = C_{ph}v^2 {}_{13}=3$, where $C_{ph} = 3S_{ph}$ is the heat capacity of phonon gas.

The main advantage of our approach is its universality. In fact till now we have not restricted ourselves to any particular dimensionality of the system or any quasiparticles dispersion. All the necessary information is contained in the corresponding relaxation times and therm odynamic quantities. This formalism allows us to analyze contributions from dimension relaxation mechanisms to the total thermal conductivity coencient. Given the dispersion relations of quasiparticles, we can easily calculate all the quantities contained in (12) – (13).

W ith Eqs. (12) - (13) we are able to address the competition between relaxation processes of the exural and phonon m odes. G lavin [14] noted that such a competition can be essential at extrem ely low temperatures if the dom inant relaxation m echanism is elastic scattering on defects, where he argued that therm al conductivity coe cient would scale as $T^{1=2}$. O ur approach allows us to study this competition comprehensively. Particularly, we predict the strong dependence of the temperature scaling exponent on the wire diam eter. The standard Ferm igolden rule approach [14] gives the m om entum dependent scattering rates for di erent modes $_{13} = W_{13} \frac{p^{1-2}}{u_1^3 a^{3-2}}$, $_{23} = W_{23} \frac{1}{pu_2^3 a^3}$; where W_{kj} are the corresponding scattering amplitudes, which depend on the physical properties of particular material. Using Eq. (15) it is easy to show, that the corresponding relaxation times scale as

$${}^{1}_{13}$$
 / a ${}^{3=2}$ T ${}^{1=2}$; ${}^{1}_{23}$ / a ${}^{5=2}$ T ${}^{1=2}$: (16)

D i erent tem perature dependence of relaxation times lead to a strong competition between two physically di erent mechanisms of them al conductivity, ux and di usive. The dom inance of one over the other strongly depends on the wire diameter at a given tem perature. To make some speci c conclusions let us sum marize the approximations done and specify the range of validity of the proposed theory. We consider a situation when therm al excitations are multiply scattered elastically while being transferred through the wire, so that other scattering mechanisms are strongly suppressed by interaction with defects. Only for this case we were able to drop relaxation within each subsystem of identical quasiparticles to obtain closed expressions (12), (13). The in uence of boundary is accounted in the dispersion of exural mode and in the dimensionality of the system. The range of tem perature is supposed to satisfy the relation T <, where 1=a is the characteristic value of the frequency gap between the adjacent phonon branches. For larger tem perature we cannot use the acoustic modes (1) only, but need to account higher branches.

In Figure 1 we can pare our theoretical results with the experimental data from [11]. We have chosen the unknown parameters W₁₃ = 12 $10^{4} \text{ m}^{5} \text{s}^{4}$ and W₂₃ = 0.9 $10^{4} \text{ m}^{5} \text{s}^{4}$ to t data for a = 22nm. Deviations from the experimental data for large diameters and temperatures show the restriction of applicability of our initial approximations. They arise from the Debye approximation and simplieed dispersion expression. Additionally, when the diameter of the wire increases, the mechanism we consider becomes less dominant. To be more precise we need to include higher excitation branches as well as another relaxation mechanisms. However our approach allows to understand the physics of the processes in the region under consideration. C learly, observed crossover is the result of competition between $_{\rm F}$ / $T^{1=2}$ and $_{\rm D}$ / T^{3} . For smaller diameters, $_{\rm F}$ is strongly dominant in the wide range of temperatures as shown on Figure 2 for wire diameter a = 2nm. Figure 3 demonstrates a complete crossover from $T^{1=2}$ to T^{3} dependence for the nanowire of a = 30nm. It can be seen that the T dependence between 20K and 40K is nearly linear, which was observed in the experiment [11]. It should be noted that T^{3} dependence of $_{\rm D}$ cannot be interpreted

in simple analogy with the bulk case. It comes not from a speci c heat directly, but from di erent sources including competition of the relaxation times in Eqs. (12), (13).

In sum mary, we derived the general analytical expressions (12) - (13), to explicitly calculate the contributions of di erent scattering mechanisms to the total relaxation of the system. The simple expressions clarify the essential elects leading to the observed behavior of them al conductivity coelecter. It is clear that the particular dispersion laws (and their reconstruction) a lect scattering rates and therm odynamic quantities. Restricted geometry and low dimensionality lead to additional scattering mechanisms. Note the information about dimensionality is naturally included in the particular form of phase space element d_i. Such a formalism helps to distinguish elects from di erent scattering mechanisms. When applied to the regime, where phonon modes compete with exural ones, our theory agrees favorably with available experimental data. Furthermore, we showed that the thermal conductivity coelected the distinguism at T^{1-2} -dependence to T^3 -dependence with increasing temperature. In view of our theoretical results it is useful to investigate smaller diameters or lower temperatures with lead to a diameters in experiment to better reveal the crossover from T^3 to T^{1-2} dependence.

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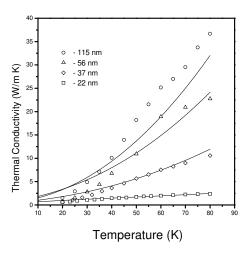


FIG.1: Therm alconductivity coe cient calculated from Eqs. (12) and (13) for di erent values of nanow ire diam eter. Experim ental data are from Ref. [11].

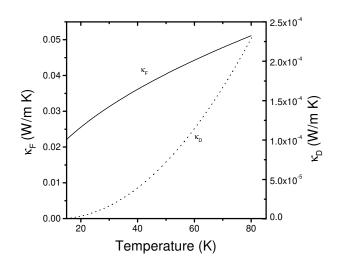


FIG.2: C om parative contribution from ux and di usive parts of therm al conductivity for a 2nm wire.

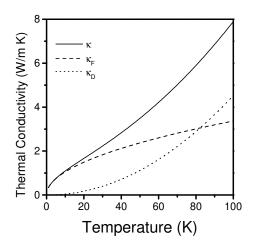


FIG.3:C rossover from T $^{1=2}$ to T 3 dependence of $\,_{\rm eff}$ for a 30nm wire.